

P-Channel Enhancement Mode Field Effect Transistor

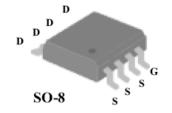
FEATURES

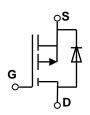
- Super high dense cell design for low RDS(ON)
- Rugged and reliable
- Simple drive requirement
- SOP-8 package

PR	PRODUCT SUMMARY					
	$V_{\rm DSS}$	ID	$Rds(ON)$ $(m \Omega)$ Typ			
	2011	0.4	15@ VGS=-10V			
	-30V	-8A	20@ VGS=-4.5V			



NOTE: The MT4435BDY is available in a lead-free package





ABSOLUTE MAXIUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-30	V
Gate-Source Voltage	Vgs	±25	V
Drain Current-Continuous ^a @Tj=125 °C	ID	-8	A
- Pulse d^b	IDM	-40	A
Drain-source Diode Forward Current ^a	Is	-2.4	A
Maximum Power Dissipation ^a	PD	2.5	W
Operating Junction and Storage Temperature Range	Тл,Тѕтс	-55 to 150	$^{\circ}$ C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to Ambient ^a Rth Ja	50	°C/W
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ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V,Id=-250µA	-30			V		
Zero Gate Voltage Drain Current	IDSS	Vds=-24V,Vgs=0V			-1	μА		
Gate-Body Leakage	Igss	V _G s=±20V,V _D s=0V			±100	nA		
ON CHARACTERITICS								
Gate Threshold Voltage	V _G s(th)	Vds=Vgs,Id=-250μA	-1	-1.6	-2.5	V		
Drain-Source On-State Resistance	D	Vgs=-10V,Id=-8A		15	17	m Ω		
Drain-Source Oil-State Resistance	RDS(ON)	Vgs=-4.5V,ID=-5.0A		20	22			
Forward Transconductance	gFS	Vgs=-15V,Id=-8A		6		S		
DAYNAMIC CHARACTERISTICS								
Input Capacitance	Ciss			1119		pF		
Output Capacitance	Coss	VDS=-15V,VGS=0V f=1.0MHz		363		pF		
Reverse Transfer Capacitance	Crss	1 1101/111		138		pF		
SWITCHING CHARACTERISISTICS								
Turn-On Delay Time	td(ON)	VDD=-15V ID=-8A, VGEN=-4.5V RL=10ohm RGEN=6ohm		17.8		ns		
Rise Time	tr			17.5		ns		
Turn-Off Delay Time	tD(OFF)			169		ns		
Fall Time	tf			96		ns		
Total Gate Charge	Q g			35		nC		
Gate-Source Charge	Qgs	Vds=-15V,Id=-1A Vds=-10V		3.3		nC		
Gate-Drain Charge	Qgd	, 55 - 10 ,		8.1		nC		



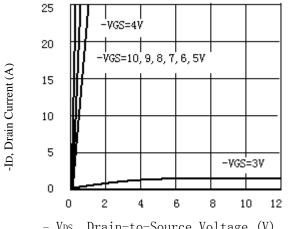
ELECTRICAL CHARACTERICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
DRAIN-SOURCE DIODE CHARACTERISTICS							
Diode Forward Voltage	Vsd	Vgs=0V,Is=-1.7A		-0.74	-1.2	V	

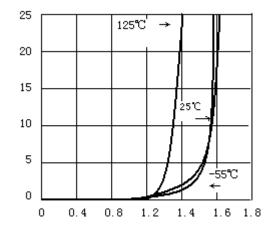
-ID, Drain Current(A)

Notes

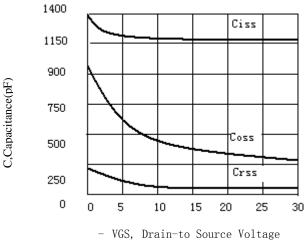
- a. Surface Mounted on FR4 Board, t≤10sec
- b. Pulse Test: Pulse Width ≤ 300Us, Duty ≤ 2%
- c. Guaranteed by design, not subject to production testing.



- VDS, Drain-to-Source Voltage (V) Figure 1. Output Characteristics



-VGS, Gate-to-source Voltage (V) Figure 2. Transfer Characteristics



- VGS, Drain-to Source Voltage Figure3. Capacitance

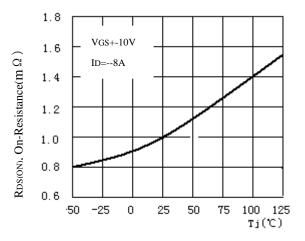
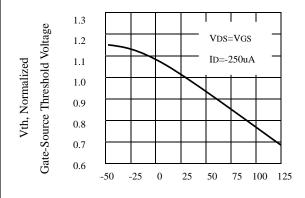
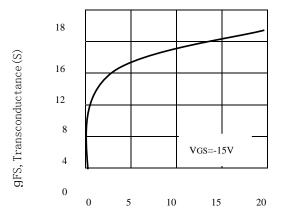


Figure 4. On-Resistance Variation with Temperature



Tj., Junction Temperature ($^{\circ}$ C) Figure 5. Gate Threshold Variation With Temperature



-IDS, Drain-Source Current (A)
Figure 7. Transconductance Variation
With Drain Current

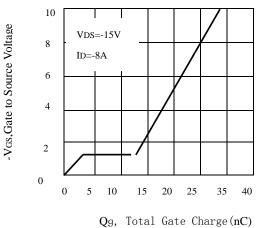
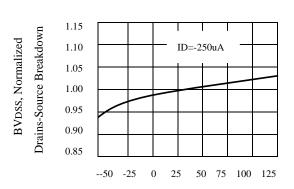
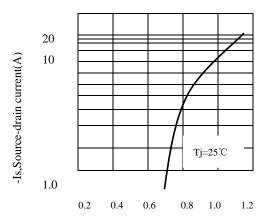


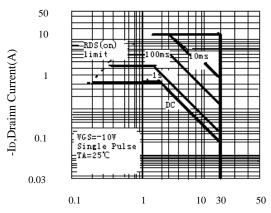
Figure 9. Gate Charge



 $Tj, \ Junction \ Temperature \ (^{\mathbb{C}})$ $Figure 6. Breakdown \ Voltage \ Variation$ $With \ Temperature$



-V_{SD}, Body Diode Forward Voltage Figure 8.Body Diode Forward Voltage Variation with Source Current



-VDS, Drain-Source Voltage(V)
Figure 10.Maximum Safe Operating Area

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